



High Power RF Solid State Amplifiers at FREIA

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Testing prototype superconducting accelerating cavities (26 SC in final LINAC), cryomodules and high power RF stations

High power RF stations at ESS specifications
352.21 MHz, 400 kW, 14 Hz, 3.5 ms, 200 kHz bandwidth





FREIA Uppsala



Cryogenics



- Liquid Nitrogen
- Helium liquefaction (150 l/h)
- 2000 I storage dewar

RF Power Stations



- 400 kW 3.5 ms pulses at 14Hz
- Dual TH595 tetrodes
- Load pull

Spoke Cavity

• Operating at 352.21 MHz

(hundrid)

111

- Q > 10⁹
- Operating gradient 9 MV/m

Control System

- Closed-loop LLRF system
- Cryogenics control



Horizontal Cryostat

- Operating at 1.8 to 4.5 K
- 16 mbar pressure



400kW RF Stations



- Tetrode based (Dual TH595)
- 400 kW 3.5 ms pulses at 14Hz
- 20 kV 40 A anode power supplies
- Class AB
- Cost Efficient/Reliability
- Efficiency a key-parameter







- No presurization and ferrite dummy loads
- Power Distribution at 3 levels
 - Half height WR2300: 400kW
 - 6-1/8 inch, 50 Ω coax: 200 kW
 - 7/8 inch, 50 Ω coax: 10 kW
- Pre amp. Efficiency: 50 55 % (class AB)
- Amp. Efficiency > 67 % (class AB)





SSA research: collaboration with NXP(now Ampleon) and ESRF







AN10967 is a demo board designed and manufactured by NXP for the BLF578 LDMOS transistor.

- push-pull configuration, class AB
- delivering 1000 W in CW
- Max efficiency: 70%
- Gain: 20 dB
- Highest temp spot: 145C (15I/min water)





1kW level Hot S-parameters measurements (pulsed)







1kW level Hot S-parameters measurements (pulsed)







- Using Hot S-parameters measurements we can characterize the output impedance at different output power levels.
- The impedance is changing quite dramatically with the output power and this needs to be taken in to account for power combination.

(BLF578 measurements realized in pulsed mode with ESS parameters)



SSA development at UU: single ended RF power amplifier – 1250 W and 70% efficiency



Tested in pulsed mode with ESS characteristics (14 Hz, 3.5 ms) delivering up to 1300 W.

- BLF188XR excellent ruggedness
- Max efficiency: 71%
- Gain: 19 dB (at 1.5 dB compression)
- Highest temp spot: 30 °C (15l/min water)
- Excellent nonlinear behavior: second harmonic at -34dBc - no balun



800

1000

1200

22

21

20

19

18

17

16

15

14

1400

Gain [dB]



Single ended RF power amplifier – 1250 W and KERE, 70% efficiency – 8 amplifiers for 10 kW demonstrator







quiescent drain current, I_{Dq} =0.1 A and drain voltage, V_{DS} =50 V.

temperature rises for only few degrees, to about 30°C

Hot S-parameters measured at different output power at 352MHz ---- Gain ---- Drain_eff





10 kW – SSA demonstrator

capacitor bank





~ 8 x 1.25 kW



Monitoring circuits:

- drain voltage
- drain current
- temperature



Combiners Planar and WG





10 kW amplifier under construction











A small variation in both gain (< 0.5 dB) and phase (< 5°) is measured for the 8 modules of the 10 kW demonstrator.

Efficiency is around 70% at 1250 W (pulsed conditions 14 Hz, 3.5 ms) Phase measurements performed using the hot S-parameters set-up.



10 kW 352 MHz amplifier





Spread among the 8 amplifiers





Power out (W)



8:1 $\lambda/4$ splitter/combiner





1:8 splitter connected to 8 loads. Circulator is used to measure RL



RL is at -41 dB level we can deduce the RL of the combiner at -32 dB



8:1 $\lambda/4$ splitter/combiner







RL is at -28 dB level

considering 1:8 splitting/combination we can deduce the RL of the combiner at -17 dB higher RL due to slightly phase and amplitude imbalances

1:8 splitter connected with circulators to the 8:1 combiner

Measured IL 0.93 dB (with cables 0.3 dB and circulator 0.2 dB) we deduce the splitter/combiner IL = 0.2 dB





Gysel Combiner





- Aluminum Casing
- High Integration Factor
- Integrated Loads
- Easily Reproducible
- Average Insertion Loss (IL): 0.2dB
- Peak Power (Tested): 10 kW

Measured Performance

		1	2	3	4	5	6	7	8
Phase [deg]		121	117	117	120	120	117	117	121
Mag [dB]		- 9.24	-9.32	-9.24	-9.16	-9.19	-9.27	-9.29	-9.15
	1		2	3	4	5	6	7	8
1	-2	1*	-24.7	-23.7	-24.2	-24.1	-23.7	-23.4	-22.7
2			-24*	-27.5	-26.8	-26.3	-24.8	-24.9	-23.6
3				-21*	-26.4	-27.3	-25.2	-24.9	-23.3
4					-23*	-30.6	-27.1	-26.1	-24.1
5						-25*	-26.2	-26.5	-24.2
6							-25*	-27.1	-23.7
7								-26*	-24.9
8									-26*





Gysel Combiner







V.A. Goryashko, D. Dancila, A. Rydberg, R. Yogi & R. Ruber (2014): A megawatt class compact power combiner for solid-state amplifiers, Journal of Electromagnetic Waves and Applications, DOI: 10.1080/09205071.2014.962187



Collaboration





Business perspective:

- commercialisation
- distribution

ACDC convertors + power supply

Water cooling system (thermal aspects)



Strategy for power combining – v1





Strategy for power combining – v2

400 kW station with major components developed at FREIA

0,6 meter





Strategy for power combining – v3

400 kW station with major components developed at FREIA

0,6 meter



Coaxial combiner 40:1

10 kW tile

8 SSA modules Gysel combiner & splitter 8:1



300 W pre-amplifier 1 SSA module 1 SSA 25 W amplifier



Conclusions



- A single ended high RF power Solid-State Amplifier was successfully designed and manufactured producing 1.25 kW with an efficiency of 70% at 352 MHz, in ESS operational mode (14 Hz, 3.5 ms). This is a simple and robust design minimizing manufacturing cost towards mass fabrication and industrialization. Joint UU - Ampleon application note.
- Measurement methods have been developed and implemented allowing hot Sparameters measurements.
- A small variation in both gain (< 0.5 dB) and phase (< 5°) is measured for the 8 modules of the 10 kW demonstrator under construction at FREIA.
- A 10 kW demonstrator, using 8 modules is finalized at FREIA. Monitoring circuits and power combiners are under development.
- <u>Strategy for the near future</u>: highly efficient class E amplifiers at 100 MHz for GE's cyclotron nucleotides production Eurostars application; possibly 400 MHz (for CERN crab cavity tests); development and amplifier design of Latch-Free LIGBT/IGBT high power transistors at UU Comheat AB (compared with LDMOS, saturation current is presently 15-30 times higher).

Joint UU - Ampleon application note on BLF188XR's site

